

1N56 Series

Silicon Avalanche Diodes

1500 Watt Metal Axial Leaded Transient Voltage Suppressors

FEATURES

- Hermetically sealed
- Breakdown voltage range 6.8 - 200 volts
- Glass passivated junction
- Excellent clamping capability
- Low zener impedance
- 100% surge tested
- -55°C to +150°C
- Uni-polar

MAXIMUM RATING

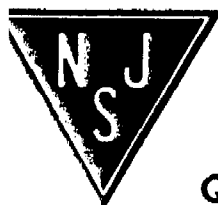
- Peak Pulse Power (Ppk): 1500 Watts (10 x 1000 μ s)@25°C (see diagram on page 3 for wave form)
- 1 watt steady state
- Response time: 1 x 10⁻¹² seconds (theoretical)
- Operating & storage temperature: -55°C to +150°C

MECHANICAL CHARACTERISTICS

- Case: Metal hermetically sealed DO-13 package
- Terminals: Axial leads, solderable per MIL-STD-202 Method 208
- Solderable leads = 230°C for 10 seconds (1.59mm from case)
- Polarity: cathode indicated by colour band
- Weight: 1.5 grammes (approx)

ELECTRICAL SPECIFICATION @ Tamb 25°C

Part Number	Reverse Stand Off Voltage V _R (Volts)	Breakdown Voltage V _{BR} (Volts) @ I _R			Maximum Reverse Leakage I _R @ V _R (μ A)	Maximum Clamping Voltage V _C @ I _{PP} (Volts)	Maximum Peak Pulse Current I _{PP} (A)	Max Voltage Temperature Variation of V _{BR} (mV/°C)
		MIN	MAX	(mA)				
1N5629*	5.50	6.12	7.48	10	1000.0	10.8	139.0	5.0
1N5629A*	5.80	6.45	7.14	10	1000.0	10.5	143.0	5.0
1N5630	6.05	6.75	8.25	10	500.0	11.7	128.0	5.0
1N5630A	6.40	7.13	7.88	10	500.0	11.3	132.0	5.0
1N5631	6.63	7.38	9.02	10	200.0	12.5	120.0	6.0
1N5631A	7.02	7.79	8.61	10	200.0	12.1	124.0	6.0
1N5632	7.37	8.19	10.00	1.0	50.0	13.8	109.0	7.0
1N5632A	7.78	8.65	9.55	1.0	50.0	13.4	112.0	7.0
1N5633	8.10	9.00	11.00	1.0	10.0	15.0	100.0	8.0
1N5633A	8.55	9.50	10.50	1.0	10.0	14.5	103.0	8.0
1N5634	8.92	9.90	12.10	1.0	5.0	16.2	93.0	9.0
1N5634A	9.40	10.50	11.60	1.0	5.0	15.6	96.0	9.0
1N5635	9.72	10.80	13.20	1.0	5.0	17.3	87.0	10.0
1N5635A	10.20	11.40	12.60	1.0	5.0	16.7	90.0	10.0
1N5636	10.50	11.70	14.30	1.0	5.0	19.0	79.0	11.0
1N5636A	11.10	12.40	13.70	1.0	5.0	18.2	82.0	11.0
1N5637*	12.10	13.50	16.50	1.0	5.0	22.0	68.0	13.0
1N5637A*	12.80	14.30	15.80	1.0	5.0	21.2	71.0	12.0
1N5638*	12.90	14.40	17.60	1.0	5.0	23.5	64.0	16.0
1N5638A*	13.60	15.20	16.80	1.0	5.0	22.5	67.0	14.0
1N5639*	14.50	16.20	19.80	1.0	5.0	26.5	56.5	17.0
1N5639A*	15.30	17.10	18.90	1.0	5.0	25.2	59.5	19.0
1N5640	16.20	18.00	22.00	1.0	5.0	29.1	51.5	20.0
1N5640A	17.10	19.00	21.00	1.0	5.0	27.7	54.0	19.0
1N5641	17.80	19.80	24.20	1.0	5.0	31.9	47.0	21.0
1N5641A	18.80	20.90	23.10	1.0	5.0	30.6	49.0	20.0
1N5642	19.40	21.60	26.40	1.0	5.0	34.7	43.0	25.0
1N5642A	20.50	22.80	25.20	1.0	5.0	33.2	45.0	23.0
1N5643*	21.80	24.30	29.70	1.0	5.0	39.1	38.5	28.0
1N5643A*	23.10	25.70	28.40	1.0	5.0	37.5	40.0	25.0
1N5644*	24.30	27.00	33.00	1.0	5.0	43.5	34.5	31.0
1N5644A	25.60	28.50	31.50	1.0	5.0	41.4	36.0	28.0
1N5645	26.80	29.70	36.30	1.0	5.0	47.7	31.5	31.0
1N5645A	28.20	31.40	34.70	1.0	5.0	45.7	33.0	30.0
1N5646*	29.10	32.40	39.60	1.0	5.0	52.0	29.0	35.0
1N5646A*	30.80	34.20	37.80	1.0	5.0	49.9	30.0	31.0



Quality Semi-Conductors

Part Number	Reverse Stand Off Voltage V_R (Volts)	Breakdown Voltage V_{BR} (Volts) @ I_T			Maximum Reverse Leakage I_R @ V_R (μA)	Maximum Clamping Voltage V_C @ I_{PP} (Volts)	Maximum Peak Pulse Current I_{PP} (A)	Max Voltage Temperature Variation of V_{BR} (mV/°C)
		MIN	MAX	(mA)				
1N5647	31.60	35.10	42.90	1.0	5.0	56.4	26.5	39.0
1N5647A	33.30	37.10	41.00	1.0	5.0	53.9	28.0	36.0
1N5648	34.80	38.70	47.30	1.0	5.0	61.9	24.0	46.0
1N5648A	36.80	40.90	45.20	1.0	5.0	59.3	25.3	44.0
1N5649*	38.10	42.30	51.70	1.0	5.0	67.8	22.2	50.0
1N5649A*	40.20	44.70	49.40	1.0	5.0	64.8	23.2	48.0
1N5650	41.30	45.90	56.10	1.0	5.0	73.5	20.4	55.0
1N5650A	43.60	48.50	53.60	1.0	5.0	70.1	21.4	51.0
1N5651	45.4	50.4	61.6	1.0	5.0	80.5	18.6	58.0
1N5651A	47.8	53.2	58.8	1.0	5.0	77.0	19.5	56.0
1N5652	50.2	55.8	68.2	1.0	5.0	89.0	16.9	65.0
1N5652A	53.0	58.9	65.1	1.0	5.0	85.0	17.7	62.0
1N5653	55.1	61.2	74.8	1.0	5.0	98.0	15.3	71.0
1N5653A	58.1	64.6	71.4	1.0	5.0	92.0	16.3	69.0
1N5654	60.7	67.5	82.5	1.0	5.0	108.0	13.9	80.0
1N5654A	64.1	71.3	78.8	1.0	5.0	103.0	14.6	76.0
1N5655*	66.4	73.8	90.2	1.0	5.0	118.0	12.7	90.0
1N5655A*	70.1	77.9	86.1	1.0	5.0	113.0	13.3	86.0
1N5656*	73.7	81.9	100.0	1.0	5.0	131.0	11.4	99.0
1N5656A*	77.8	86.5	95.5	1.0	5.0	125.0	12.0	94.0
1N5657	81.0	90.0	110.0	1.0	5.0	144.0	10.4	109.0
1N5657A	85.5	95.0	105.0	1.0	5.0	137.0	11.0	104.0
1N5658	89.2	99.0	121.0	1.0	5.0	158.0	9.5	120.0
1N5658A	94.0	105.0	116.0	1.0	5.0	152.0	9.9	115.0
1N5659	97.2	108.0	132.0	1.0	5.0	173.0	8.7	131.0
1N5659A	102.0	114.0	126.0	1.0	5.0	165.0	9.1	125.0
1N5660*	105.0	117.0	143.0	1.0	5.0	187.0	8.0	142.0
1N5660A*	111.0	124.0	137.0	1.0	5.0	179.0	8.4	136.0
1N5661	121.0	135.0	165.0	1.0	5.0	215.0	7.0	164.0
1N5661A	128.0	143.0	158.0	1.0	5.0	207.0	7.2	157.0
1N5662	130.0	144.0	176.0	1.0	5.0	230.0	6.5	175.0
1N5662A	136.0	152.0	168.0	1.0	5.0	219.0	6.8	167.0
1N5663	138.0	153.0	187.0	1.0	5.0	244.0	6.2	186.0
1N5663A	145.0	162.0	179.0	1.0	5.0	234.0	6.4	188.0
1N5664	146.0	162.0	198.0	1.0	5.0	258.0	5.8	197.0
1N5664A	154.0	171.0	189.0	1.0	5.0	246.0	6.1	188.0
1N5665	162.0	180.0	220.0	1.0	5.0	287.0	5.2	219.0
1N5665A	171.0	190.0	210.0	1.0	5.0	274.0	5.5	209.0

Suffix 'A' denotes 5% tolerance device, no suffix denotes a 10% tolerance device.

* V_{BR} is measured after I_T has been applied for <300 ms

Forward voltage V_F , at $I_F = 1$ AMP, 1.2V max.

Forward current I_F shall be applied for 30 secs. before V_F is measured.

MECHANICAL CHARACTERISTICS

CASE: DO-13, welded, hermetically sealed metal and glass.

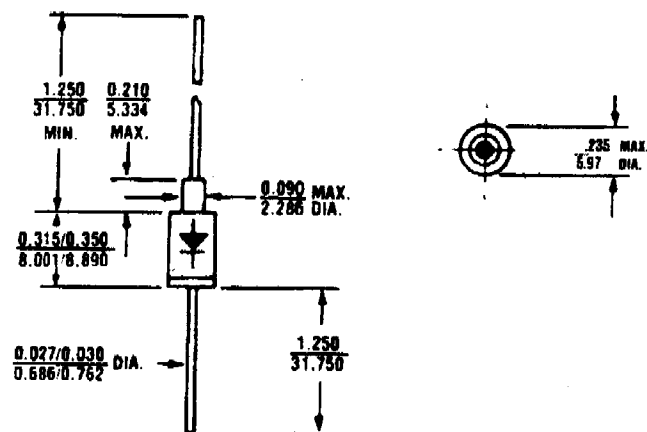
FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 50°C/W (Typical) junction to lead at 0.375-inches from body.

POLARITY: Cathode connected to case. Polarity indicated by diode symbol.

WEIGHT: 1.4 grams (Appx.)

MOUNTING POSITION: Any.



All dimensions in INCH
m.m.